

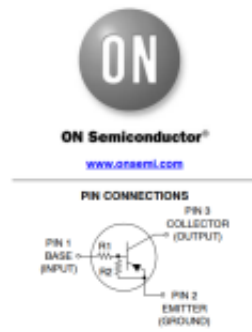
Link do produktu: <https://tranzystorek.pl/smmun2134lt1g50v-80-100ma-246mw-sot-23-3to-236-3-single-pre-biased-bipolar-transistors-rohs-p-99.html>

**MUN2134, MMUN2134L,  
MUN5134, DTA124XE,  
DTA124XM3, NSBA124XF3**

**Digital Transistors (BRT)  
R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$**

**PNP Transistors with Monolithic Bias Resistor Network**

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors, a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.



## SMMUN2134LT1G50V 80 100mA 246mW SOT-23-3(TO-236-3) Single, Pre-Biased Bipolar Transistors RoHS

Cena brutto	<b>0,37 zł</b>
Cena netto	<b>0,30 zł</b>
Dostępność	<b>Dostępny</b>
Czas wysyłki	<b>48 godzin</b>
Numer katalogowy	<b>SMMUN2134LT1G</b>

### Opis produktu

Producent: onsemi  
Obudowa: SOT-23-3 (TO-236-3)  
Temperatura pracy: -55°C~+150°C  
Napięcie kolektor-emiter: VCEO: 50 V  
Wzmocnienie prądowe DC: 80  
Prąd kolektora (Ic): 100 mA  
Rezystor wejściowy: 22 k $\Omega$   
Współczynnik rezystancji: 0,47  
Liczba: -  
Pd: strata mocy: 246 mW

Produkt posiada dodatkowe opcje:

**Obudowa:** SOT23